NSN 5961-00-216-4420

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-216-4420
Inclosure Material:
Metal
Overall Length:
1.480 inches
Overall Diameter:
0.850 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Overall Width Across Flats:
0.870 inches
Thread Size:
0.312 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector to base voltage, dc and 80.0 collector to emitter voltage, dc and 8.0 emitter to base voltage, dc and 0.6 collector to
emitter saturation voltage
Current Rating Per Characteristic:
10.00 microamperes zero-gate-voltage source current preset and 20.00 amperes source cutoff current
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector preset
Transfer Ratio:
40.0 small-signal short-circuit forward current transfer ratio, common-emitter and 120.0 small-signal short-circuit forward current transfer
ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
70143-1300176 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a

Unit Of Measure:

NSN 5961-00-216-4420

Transistor - Page 2 of 2



_		••	• •				
וו	em	ш	112	rız	211	n	٠.

No

Fiig:

A110a0